TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

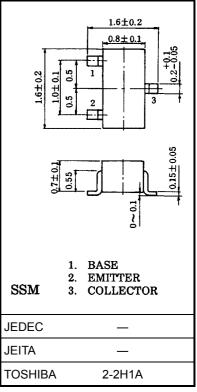
# 2SC5111

For VCO Application

Unit: mm

### **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V <sub>CBO</sub>	20	V	
Collector-emitter voltage	V <sub>CEO</sub>	10	V	
Emitter-base voltage	V <sub>EBO</sub>	3	V	
Base current	Ι <sub>Β</sub>	30	mA	
Collector current	I <sub>C</sub>	60	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T <sub>stg</sub>	<b>−55~125</b>	°C	



Weight: 2.4 mg (typ.)

### **Electrical Characteristics (Ta = 25°C)**

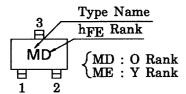
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0	_	_	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 1 V, I <sub>C</sub> = 0	_	_	0.1	μА
DC current gain	h <sub>FE</sub> (Note 1)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 mA	80	_	240	
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 mA	4	6	_	GHz
Insertion gain	S <sub>21e</sub>   <sup>2</sup>	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	7	11	_	dB
Output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0, f = 1 MHz (Note 2)	_	0.7	_	pF
Reverse transfer capacitance	C <sub>re</sub>	$\frac{1}{2}$ VCB = $\frac{1}{2}$ V, $\frac{1}{1}$ = 0, $\frac{1}{1}$ = 1 MIDZ (NOTE 2)	_	0.5	0.9	pF
Collector-base time constant	C <sub>c</sub> .rbb'	V <sub>CB</sub> = 5 V, I <sub>C</sub> = 3 mA, f = 30 MHz	_	5.5	10	ps

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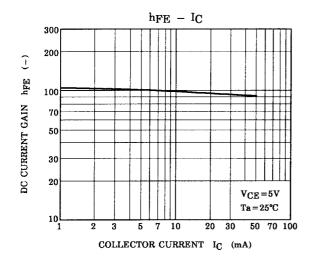
Note 1: hFE classification O: 80~160, Y: 120~240

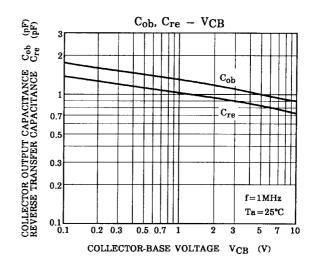
Note 2:  $C_{\text{re}}$  is measured by 3 terminal method with capacitance bridge.

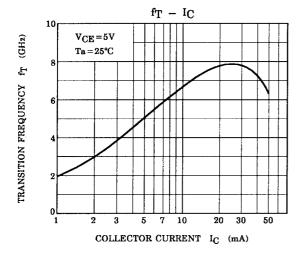
## Marking

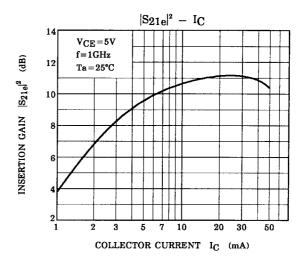


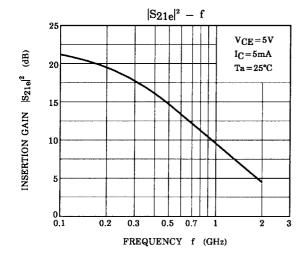
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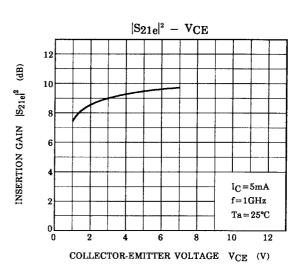


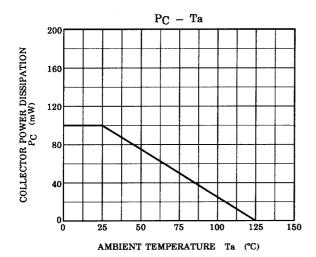












## S-Parameter $Z_O = 50 \Omega$ , $Ta = 25^{\circ}C$

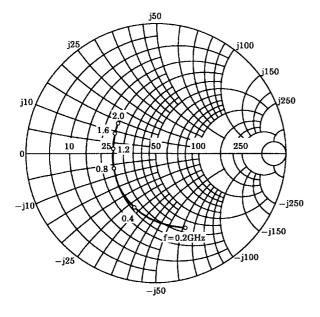
### $V_{CE} = 5 V$ , $I_C = 5 mA$

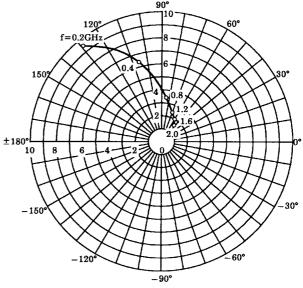
Frequency	S	11	S	21	S	12	SZ	22
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.631	-67.7	9.526	129.8	0.062	55.9	0.687	-38.7
400	0.441	-111.7	6.393	106.3	0.084	49.5	0.459	-48.5
600	0.363	-139.8	4.611	93.6	0.100	50.6	0.360	-50.6
800	0.338	-159.8	3.599	84.6	0.117	52.9	0.312	-51.1
1000	0.331	-175.0	2.990	77.5	0.134	55.1	0.286	-51.6
1200	0.337	171.9	2.556	71.2	0.152	57.2	0.271	-53.0
1400	0.344	161.7	2.252	65.3	0.174	58.6	0.265	-55.7
1600	0.359	152.1	2.011	60.3	0.196	58.5	0.259	-59.5
1800	0.373	144.6	1.845	55.4	0.217	57.9	0.254	-63.6
2000	0.391	138.5	1.691	50.8	0.238	58.3	0.249	-68.8

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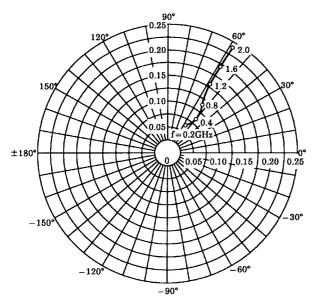
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$ 

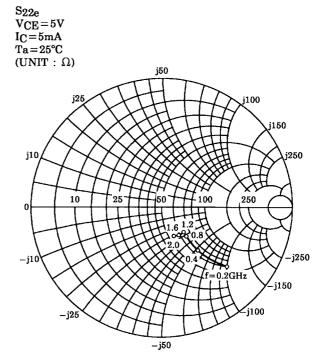
 $S_{21e}$   $V_{CE} = 5V$   $I_{C} = 5mA$   $T_{a} = 25^{\circ}C$ 





 $S_{12e}$   $V_{CE} = 5V$   $I_{C} = 5mA$  $T_{a} = 25^{\circ}C$ 





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